

# P46LF7R5SNK

## Power MOSFETs

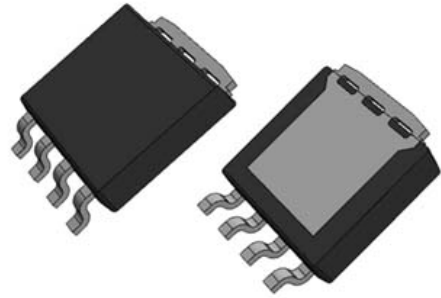
75V, 46A, N-channel

### Feature

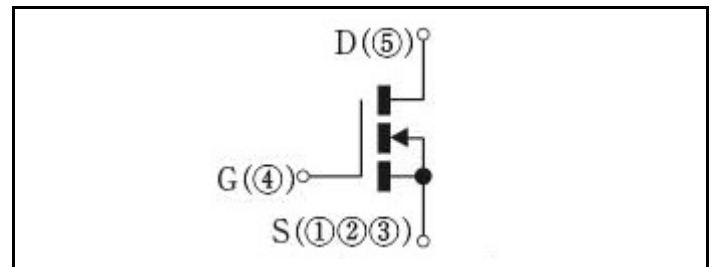
- N-channel
- Small SMD
- Large Current
- Low Ron
- 10V Gate Drive
- Low Capacitance
- Based on AEC-Q101
- Halogen free
- Pb free terminal
- RoHS:Yes

### OUTLINE

Package (House Name): LF  
 Package (JEDEC Code): MO-235B similar



### Equivalent circuit



### Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

| Item                           | Symbol           | Conditions  | Ratings    | Unit |
|--------------------------------|------------------|---|------------|------|
| Storage temperature            | Tstg             |   | -55 to 175 | °C   |
| Channel temperature            | Tch              |   | -55 to 175 | °C   |
| Drain-source voltage           | V <sub>DSS</sub> |   | 75         | V    |
| Gate-source voltage            | V <sub>GSS</sub> |   | ±20        | V    |
| Continuous drain current(DC)   | I <sub>D</sub>   |   | 46         | A    |
| Continuous drain current(Peak) | I <sub>DP</sub>  | Pulse width 10μs, duty=1/100                          | 138        | A    |
| Total power dissipation        | P <sub>T</sub>   |   | 168        | W    |
| Single avalanche current       | I <sub>AS</sub>  | Starting T <sub>ch</sub> =25°C T <sub>ch</sub> ≤150°C | 28         | A    |
| Single avalanche energy        | E <sub>AS</sub>  | Starting T <sub>ch</sub> =25°C T <sub>ch</sub> ≤150°C | 88         | mJ   |

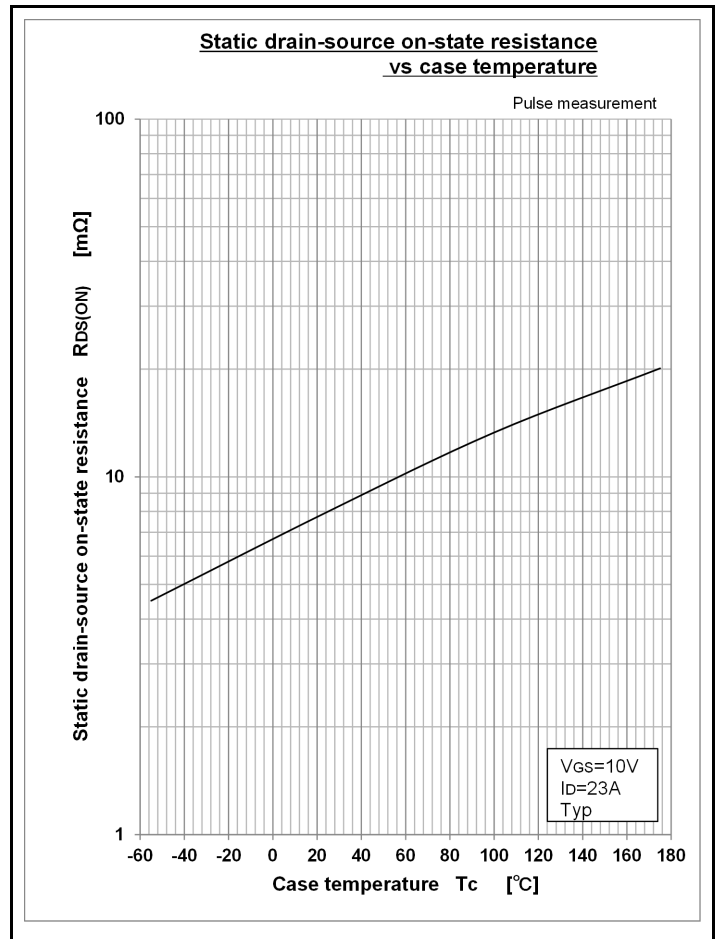
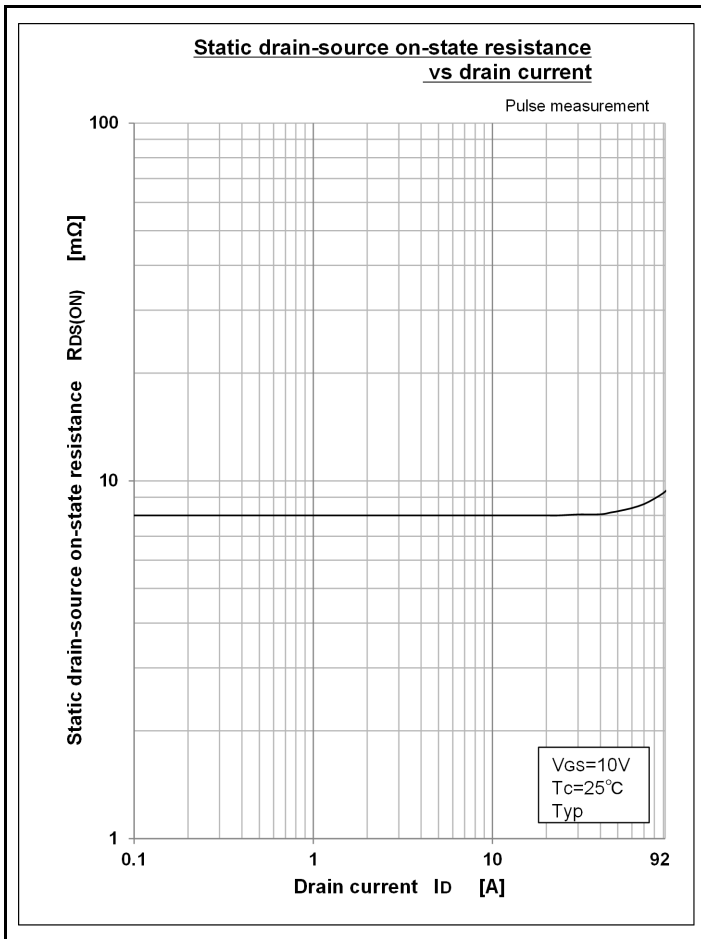
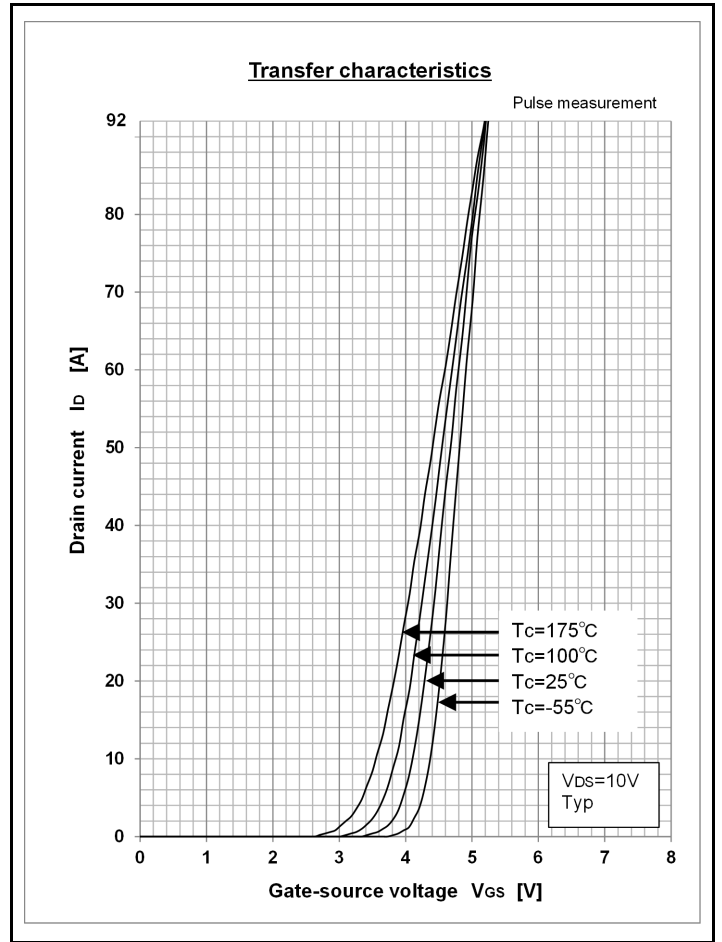
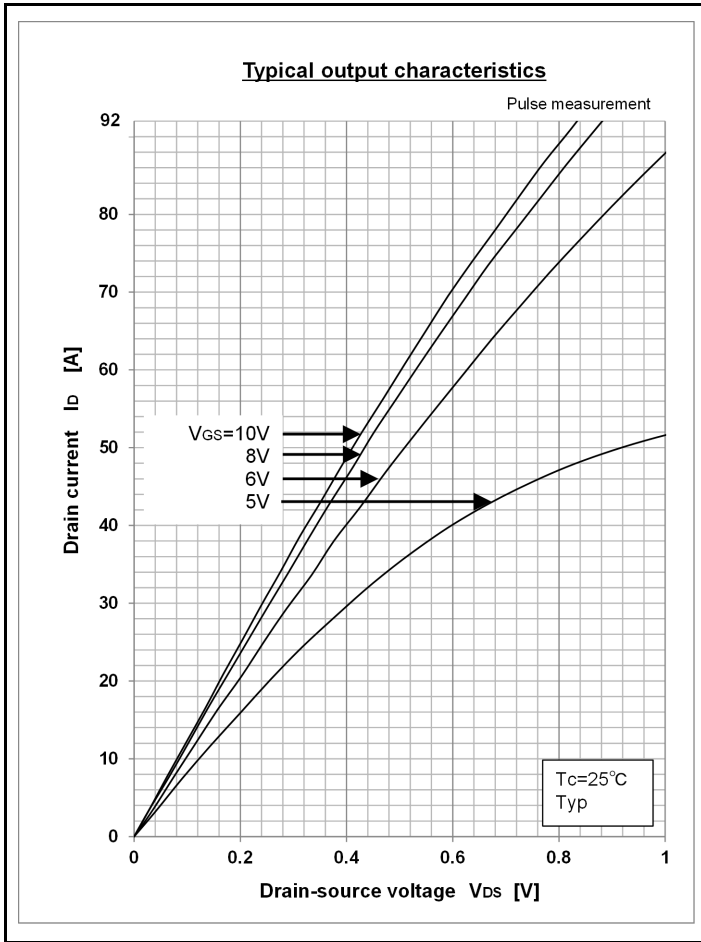
\* : See the original Specifications

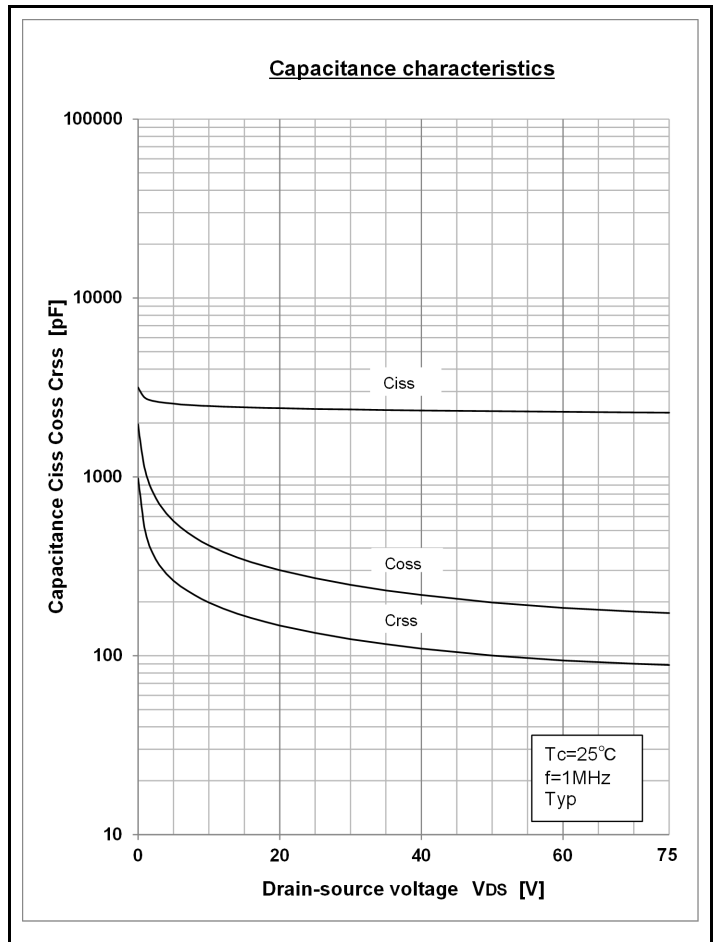
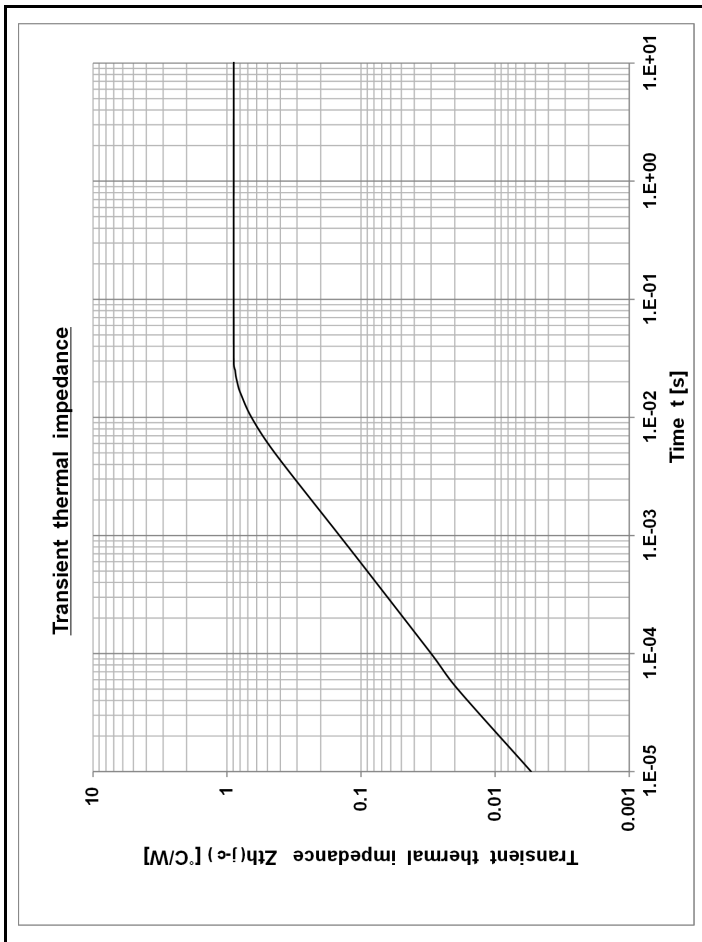
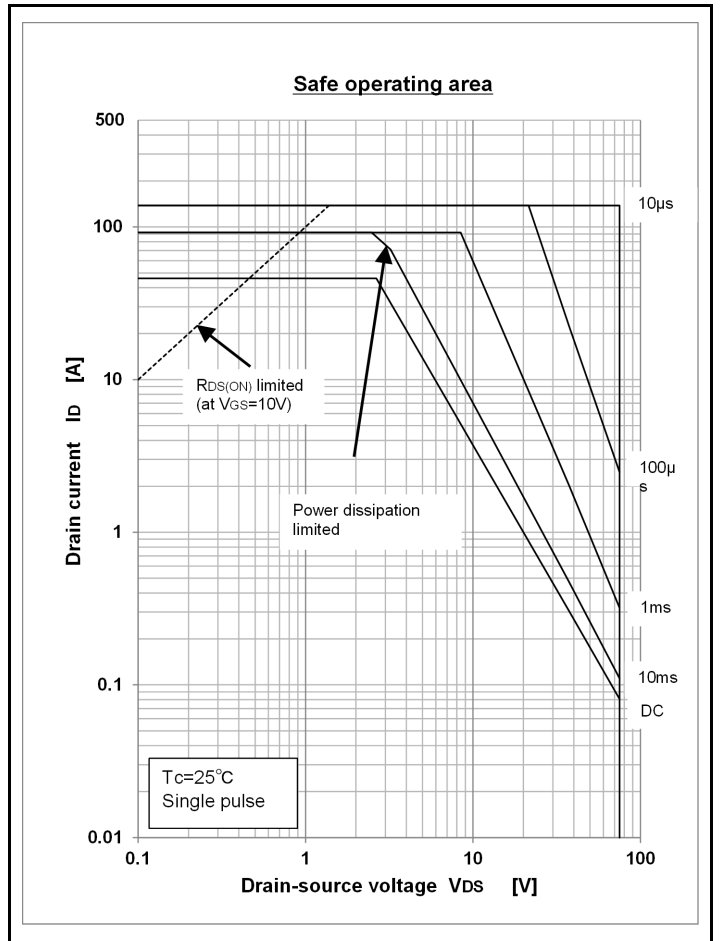
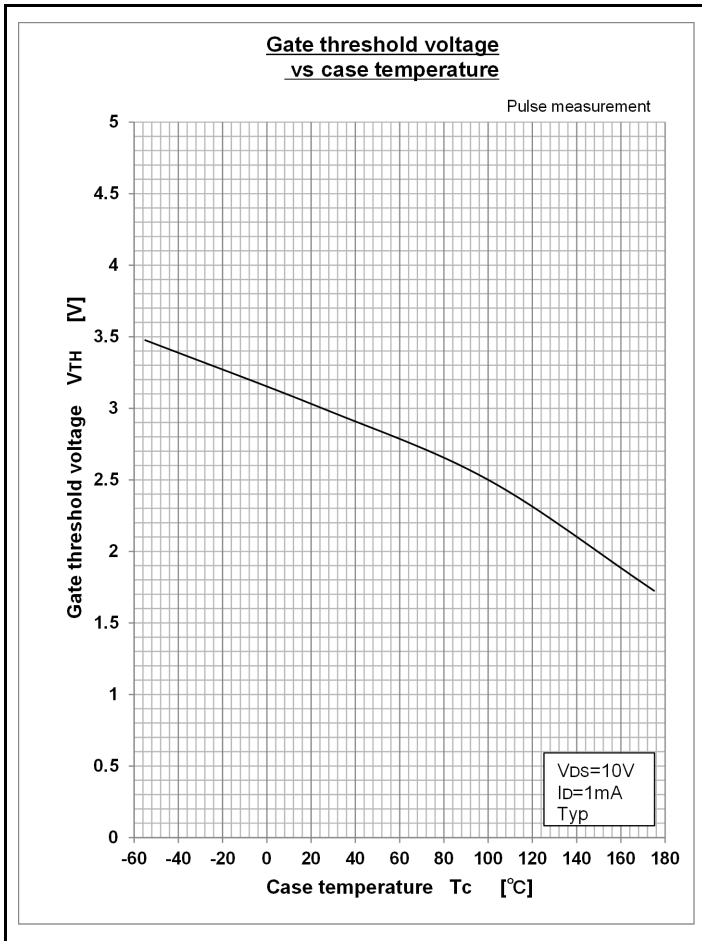
**Electrical Characteristics** (unless otherwise specified : Tc=25°C)

| Item                                    | Symbol        | Conditions  | Ratings |       |      | Unit |
|---|---------------|---|---------|-------|------|------|
|   |               |   | MIN     | TYP   | MAX  |      |
| Drain-Source breakdown voltage          | $V_{(BR)DSS}$ | ID=1mA, VGS=0V  | 75      |       |      | V    |
| Zero gate voltage drain current         | $I_{DSS}$     | VDS=75V, VGS=0V   |         |       | 1    | μA   |
| Gate-source leakage current             | $I_{GSS}$     | VGS=±20V, VDS=0V  |         |       | ±0.1 | μA   |
| Forward transconductance                | $g_{fs}$      | ID=23A, VDS=10V   | 10      |       |      | S    |
| Static drain-source on-state resistance | $R_{DS(ON)}$  | ID=23A, VGS=10V   |         | 0.008 | 0.01 | Ω    |
| Gate threshold voltage                  | $V_{th}$      | ID=1mA, VDS=10V   | 2       | 3     | 4    | V    |
| Source-drain diode forward voltage      | $V_{SD}$      | IS=46A, VGS=0V  |         |       | 1.5  | V    |
| Thermal resistance                      | $R_{th(j-c)}$ | Junction to case, with heatsink                           |         |       | 0.89 | °C/W |
| Total gate charge                       | $Q_g$         | VDD=60V, VGS=10V, ID=46A                                  |         | 48    |      | nC   |
| Gate to source charge                   | $Q_{gs}$      | VDD=60V, VGS=10V, ID=46A                                  |         | 13.5  |      | nC   |
| Gate to drain charge                    | $Q_{gd}$      | VDD=60V, VGS=10V, ID=46A                                  |         | 17    |      | nC   |
| Input capacitance                       | $C_{iss}$     | VDS=25V, VGS=0V, f=1MHz                                   |         | 2380  |      | pF   |
| Reverse transfer capacitance            | $C_{rss}$     | VDS=25V, VGS=0V, f=1MHz                                   |         | 132   |      | pF   |
| Output capacitance                      | $C_{oss}$     | VDS=25V, VGS=0V, f=1MHz                                   |         | 272   |      | pF   |
| Turn-on delay time                      | $t_{d(on)}$   | ID=23A, RL=1.63Ω, VDD=37.5V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V |         | 5.7   |      | ns   |
| Rise time                               | $t_r$         | ID=23A, RL=1.63Ω, VDD=37.5V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V |         | 10.5  |      | ns   |
| Turn-off delay time                     | $t_{d(off)}$  | ID=23A, RL=1.63Ω, VDD=37.5V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V |         | 29    |      | ns   |
| Fall time                               | $t_f$         | ID=23A, RL=1.63Ω, VDD=37.5V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V |         | 10.5  |      | ns   |
| Diode reverse recovery time             | $t_{rr}$      | IF=46A, VGS=0V, di/dt=100A/μs                             |         | 46    |      | ns   |
| Diode reverse recovery charge           | $Q_{rr}$      | IF=46A, VGS=0V, di/dt=100A/μs                             |         | 67    |      | nC   |

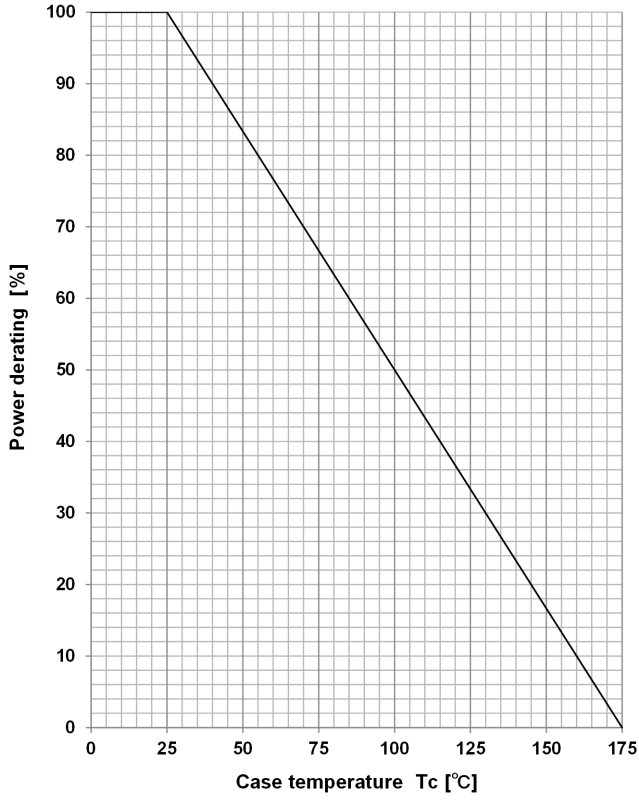
※ : See the original Specifications

# CHARACTERISTIC DIAGRAMS

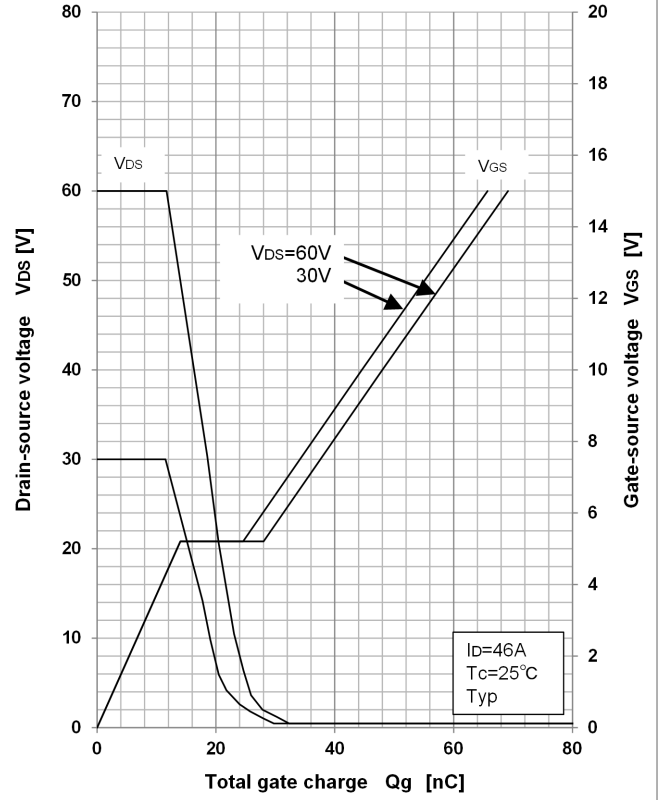




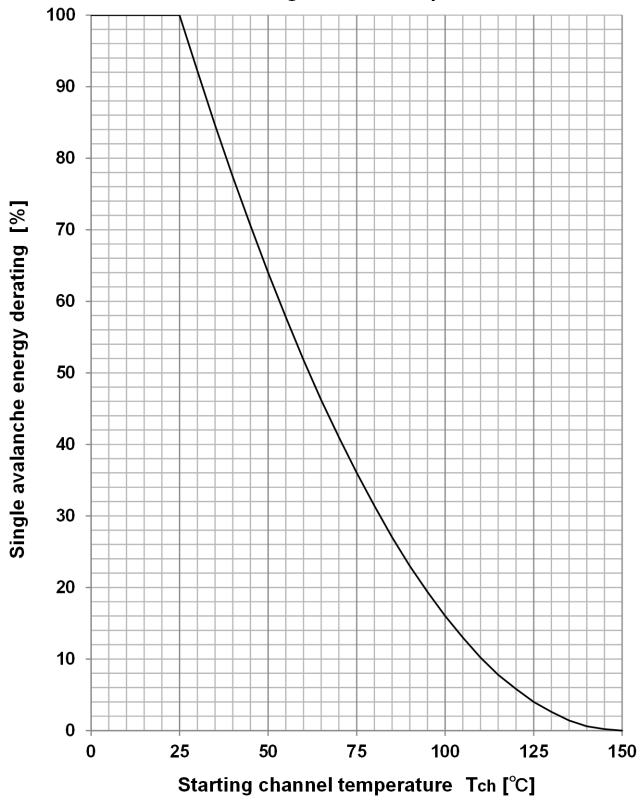
**Power derating vs case temperature**



**Gate charge characteristics**

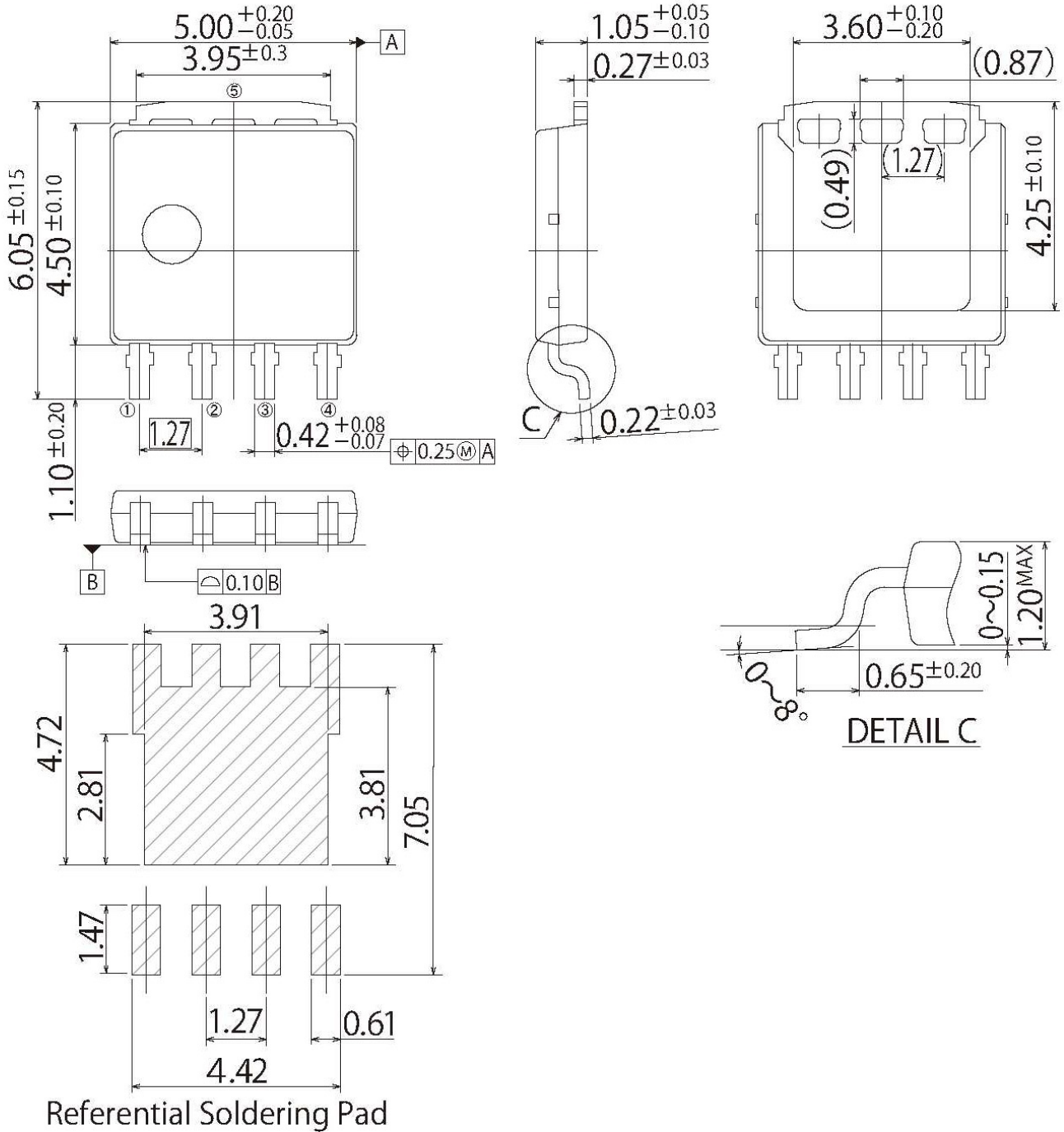


**Single avalanche energy derating vs starting channel temperature**



G7

|            |                 |
|------------|-----------------|
| JEDEC Code | MO-235B similar |
| JEITA Code | —               |
| House Name | LF              |



## Notes

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